

Preservo amplifier for CD players

BA6387K

The BA6387K is a preservo amplifier for CD players. By using this paired with a ROHM DSP, a servo and main signal system can be configured with few external components and low power consumption.

●Applications

CD players

●Features

- 1) Internal RF and AGC circuits.
- 2) Internal APC circuit.
- 3) Internal auto asymmetry circuit.
- 4) Internal disc defect detector.
- 5) Internal focus protect function against disc defects.

●Absolute maximum ratings (Ta = 25°C)

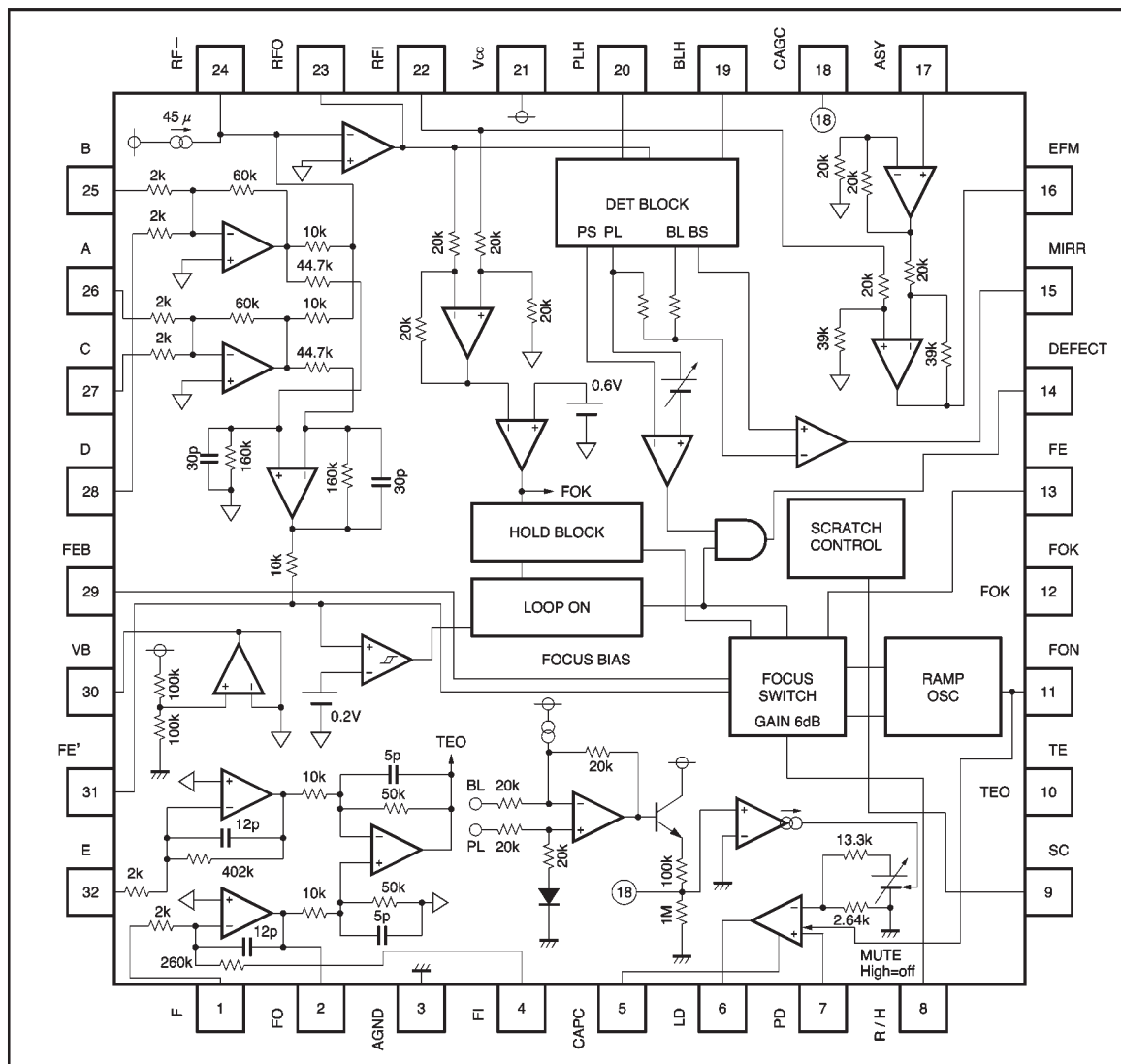
| Parameter | Symbol | Limits | Unit |
|-----------------------|------------------|----------|------|
| Power supply voltage | V _{CC} | 9 | V |
| Power dissipation | P _d | 400 * | mW |
| Operating temperature | T _{opr} | −25~+75 | °C |
| Storage temperature | T _{stg} | −55~+125 | °C |

* Reduced by 4mW for each increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Ta = 25°C)

| Parameter | Symbol | Limits | Unit |
|----------------------|-----------------|---------|------|
| Power supply voltage | V _{CC} | 2.5~5.5 | V |

● Block diagram



● Pin descriptions

| Pin No. | Pin name | Function |
|---------|----------|---|
| 1 | F | F input |
| 2 | FO | F output |
| 3 | AGND | Analog GND |
| 4 | FI | F gain adjustment feedback |
| 5 | CAPC | For capacitor for APC phase compensation |
| 6 | LD | APC amplifier output |
| 7 | PD | APC amplifier input |
| 8 | R / H | For capacitor for ramp wave/ loop off |
| 9 | SC | For resistor for scratch depth adjustment |
| 10 | TE | Tracking error output |
| 11 | FON | Focus on control |
| 12 | FOK | Focus OK comparator output |
| 13 | FE | Focus error output 1 |
| 14 | DETECT | Defect signal output |
| 15 | MIRR | Mirror signal output |
| 16 | EFM | EFM signal output |

| Pin No. | Pin name | Function |
|---------|-----------------|-------------------------------------|
| 17 | ASY | Auto-asymmetry control input |
| 18 | CAGC | For capacitor for AGC constant |
| 19 | BLH | For capacitor for bottom long |
| 20 | PLH | For capacitor for peak long |
| 21 | V _{CC} | Power supply |
| 22 | RFI | RF output capacity coupling reinput |
| 23 | RFO | RF summing amplifier output |
| 24 | RF— | RF summing amplifier feedback input |
| 25 | B | B input |
| 26 | A | A input |
| 27 | C | C input |
| 28 | D | D input |
| 29 | FEB | Focus error bias input |
| 30 | VB | Bias amplifier output |
| 31 | FE' | Focus error output 2 |
| 32 | E | E input |

●Electrical characteristics (unless otherwise noted, Ta = 25°C and V_{CC} = 2.5V)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|-------------------------------------|--------------------|-------|-------|-------|------|--|
| Quiescent current | I _Q | — | 8.7 | 12.7 | mA | — |
| 〈Bias amplifier〉 | | | | | | |
| Bias voltage | V _B | 1.12 | 1.25 | 1.38 | V | — |
| Maximum output high level voltage | I _{OH} | 3.0 | — | — | mA | Bias fluctuation below 200mV |
| Maximum output low level voltage | I _{OL} | 3.0 | — | — | mA | Bias fluctuation below 200mV |
| 〈RF amplifier〉 | | | | | | |
| Output offset voltage | V _{OFFRF} | −1.02 | −0.90 | −0.78 | V | * |
| Voltage gain | G _{RF} | 21.0 | 24.0 | 27.0 | dB | V ₈ =0.8V, SG5=30mV _{P-P} , 1kHz |
| Maximum output high level amplitude | V _{OHRF} | 0.90 | 1.10 | — | V | Simultaneous AC and BD input |
| Maximum output low level amplitude | V _{OLRF} | — | −1.10 | −0.90 | V | V ₉ =V _B +0.25V, V _B −0.05V * |
| Cutoff frequency | F _{CRF} | — | 6 | — | MHz | −3dB point |
| 〈FE amplifier〉 | | | | | | |
| Output offset voltage | V _{OFFE} | −80 | 0 | 80 | mV | * |
| Voltage gain AC | G _{FEAC} | 26 | 29 | 32 | dB | SG5=30mV _{P-P} , 1kHz |
| Voltage gain BD | G _{FEBD} | 26 | 29 | 32 | dB | SG6=30mV _{P-P} , 1kHz |
| Voltage gain difference | ΔG _{FE} | −3 | 0 | 3 | dB | — |
| Maximum output high level amplitude | V _{OHE} | 0.90 | 1.10 | — | V | Measurement with AC and BD input |
| Maximum output low level amplitude | V _{OLFE} | — | −1.10 | −0.90 | V | V ₉ (V ₁₀) = V _B ±0.15V * |
| Frequency characteristics | F _{CFE} | 19 | 22 | 25 | dB | SG5 (SG6) =60mV _{P-P} , 60kHz |
| 〈TE amplifier〉 | | | | | | |
| Output offset voltage | V _{OFFTE} | −80 | 0 | 80 | mV | * |
| Voltage gain E | G _{TEE} | 27 | 30 | 33 | dB | SG1=30mV _{P-P} , 1kHz |
| Voltage gain F | G _{TEF} | 27 | 30 | 33 | dB | SG2=30mV _{P-P} , 1kHz |
| Voltage gain difference | ΔG _{TE} | −3 | 0 | 3 | dB | — |
| Maximum output high level amplitude | V _{OHTE} | 0.90 | 1.10 | — | V | V ₁ =V _B +0.1V * |
| Maximum output low level amplitude | V _{OLTE} | — | −1.10 | −0.90 | V | V ₂ =V _B +0.1V * |
| Frequency characteristics | F _{CTE} | 19 | 22 | 25 | dB | SG1 (SG2) =60mV _{P-P} , 60kHz |
| 〈FOK comparator〉 | | | | | | |
| Input pin 22 | | | | | | |
| Threshold voltage | V _{THFK} | −0.42 | −0.30 | −0.18 | V | * |
| Output high level voltage | V _{OHFK} | 2.0 | — | — | V | V ₇ =V _B −0.42V |
| Output low level voltage | V _{OLFK} | — | — | 0.5 | V | V ₇ =V _B −0.18V |
| Maximum operating frequency | F _{MXFK} | 45 | — | — | kHz | — |
| 〈Asymmetry amplifier〉 | | | | | | |
| Output offset voltage | V _{OFAS} | −60 | — | 60 | mV | * |
| Voltage gain 1 | G _{1AS} | 3 | 6 | 9 | dB | Input pin 22, 80mV _{P-P} , 1kHz |
| Voltage gain 2 | G _{2AS} | 8.5 | 11.5 | 14.5 | dB | Input pin 17, 80mV _{P-P} , 1kHz |
| Maximum output high level amplitude | V _{OHAS} | 0.90 | 1.10 | — | V | V ₇ =V _B ±0.8 |
| Maximum output low level amplitude | V _{OLAS} | — | −1.10 | −0.90 | V | V ₆ =V _B ±0.4 * |

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|---------------------------------|-------------------|------|------|------|------------------|---|
| 〈APC〉 | | | | | | |
| Output voltage 1 | V _{O1AP} | 1.90 | 2.30 | — | V | 230mV input at pin 7 |
| Output voltage 2 | V _{O2AP} | — | 1.0 | 1.4 | V | 170mV input at pin 7, I ₂ =1mA |
| Reference voltage | V _{APR} | 190 | 200 | 210 | mV | — |
| Frequency characteristics | F _{AP} | —5 | —1 | 3 | dB | SG7=40mV _{P-P} , 500Hz |
| 〈AGC〉 | | | | | | |
| Reference voltage 1 | V _{AGC1} | 0 | — | 100 | mV | V8=0.8V, RFO=1.2V _{P-P} |
| Reference voltage 2 | V _{AGC2} | 180 | 195 | 210 | mV | V8=0.8V, RFO=0.7V _{P-P} |
| Attack time | R _{ATT} | 70 | 100 | 130 | kΩ | Measurement of internal R |
| Recovery time | R _{RCV} | 0.7 | 1.0 | 1.3 | MΩ | |
| 〈Mirror detector〉 | | | | | | |
| Output high level voltage | V _{OHMR} | 2.0 | — | — | V | R _L =15kΩ |
| Output low level voltage | V _{OLMR} | — | — | 0.5 | V | — |
| Minimum operating frequency | F _{MNMR} | — | — | 600 | Hz | — |
| Maximum operating frequency | F _{MXMR} | 30 | — | — | kHz | — |
| Minimum input operating voltage | V _{MNMR} | — | — | 0.2 | V _{P-P} | — |
| Maximum input operating voltage | V _{MXMR} | 1.2 | — | — | V _{P-P} | — |
| 〈Defect detector〉 | | | | | | |
| Output high level voltage | V _{OHDF} | 2.0 | — | — | V | R _L =15kΩ |
| Output low level voltage | V _{OLDF} | — | — | 0.5 | V | — |
| Minimum operating frequency | F _{MNDF} | — | — | 1 | kHz | — |
| Maximum operating frequency | F _{MXDF} | 2 | — | — | kHz | — |
| Minimum input operating voltage | V _{MNDF} | — | — | 0.5 | V _{P-P} | — |
| Maximum input operating voltage | V _{MXDF} | 1.2 | — | — | V _{P-P} | — |
| Scratch depth | V _{SC} | 0.13 | 0.20 | 0.27 | V | — |
| 〈Ramp wave generator circuit〉 | | | | | | |
| Period | I _{SIRA} | 220 | 340 | 460 | ms | — |
| High level limit voltage | V _{LHRA} | 80 | 124 | 168 | mV | FEO output value |
| Low level limit voltage | V _{LLRA} | —168 | —124 | —80 | mV | |
| 〈FON pin〉 | | | | | | |
| Inflow current | I _{FON} | 10.4 | 13.5 | 16.6 | μA | — |
| Input threshold voltage | V _{THFO} | 1.10 | 1.45 | 1.80 | V | — |
| 〈Loop on unit〉 | | | | | | |
| Loop off delay time | t _{OFLO} | 4.0 | 6.6 | 10.0 | ms | — |
| 〈FZC comparator〉 | | | | | | |
| Input sensitivity level | V _{FZH} | 320 | 400 | 480 | mV | — |
| Zero cross sensitivity level | V _{FZL} | 120 | 200 | 280 | mV | — |

* Standards are with V_s reference.

※When FON is LOW, 8 voltage is V_s.

※The ramp wave begins at the bottom.

※The loop will not turn on when the ramp wave is at the bottom.

※Pin 8 is charged rapidly when the loop turns on.

● Measurement circuit

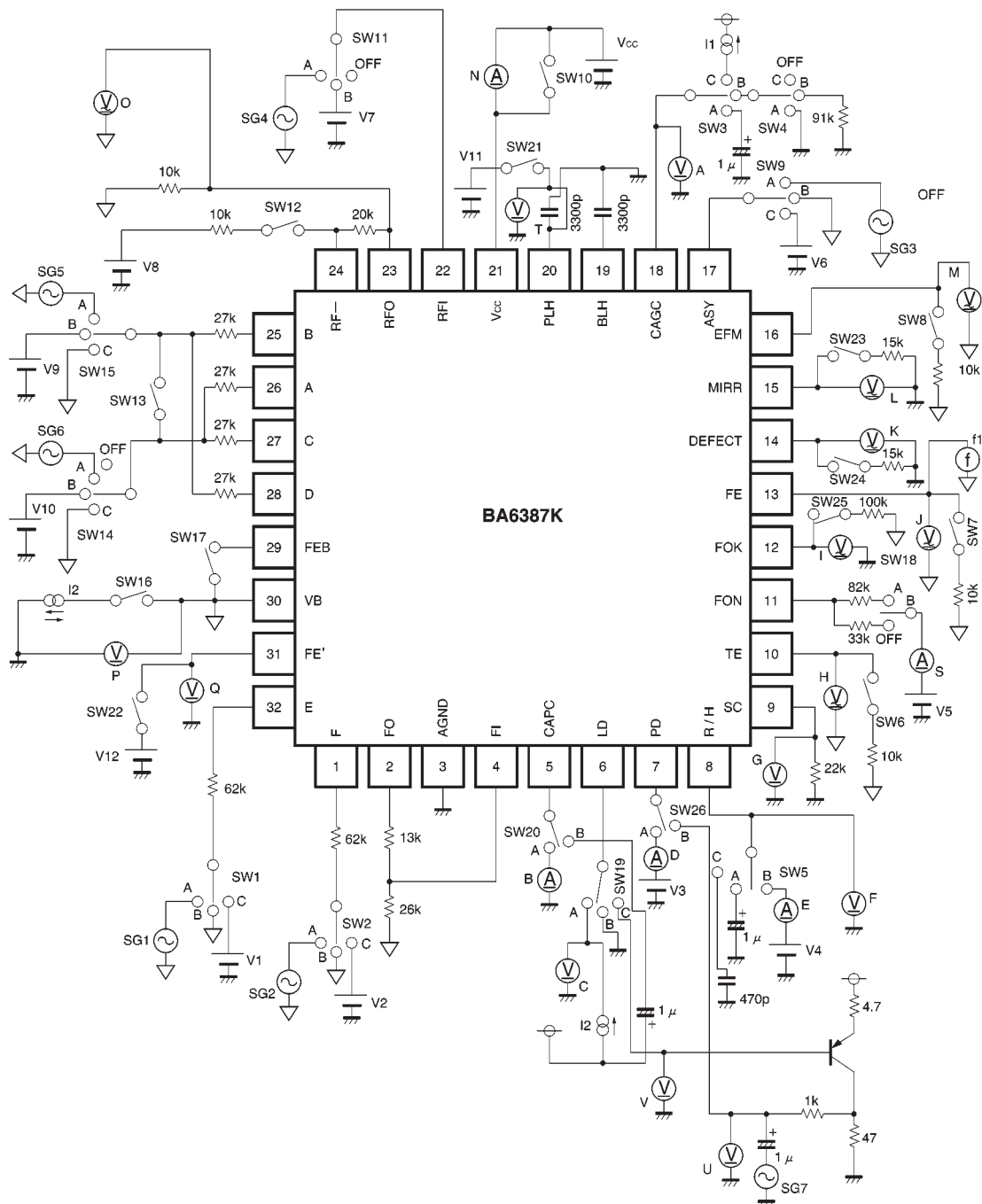


Fig.1

● Circuit operation

(1) RF amplifier, FOK comparator

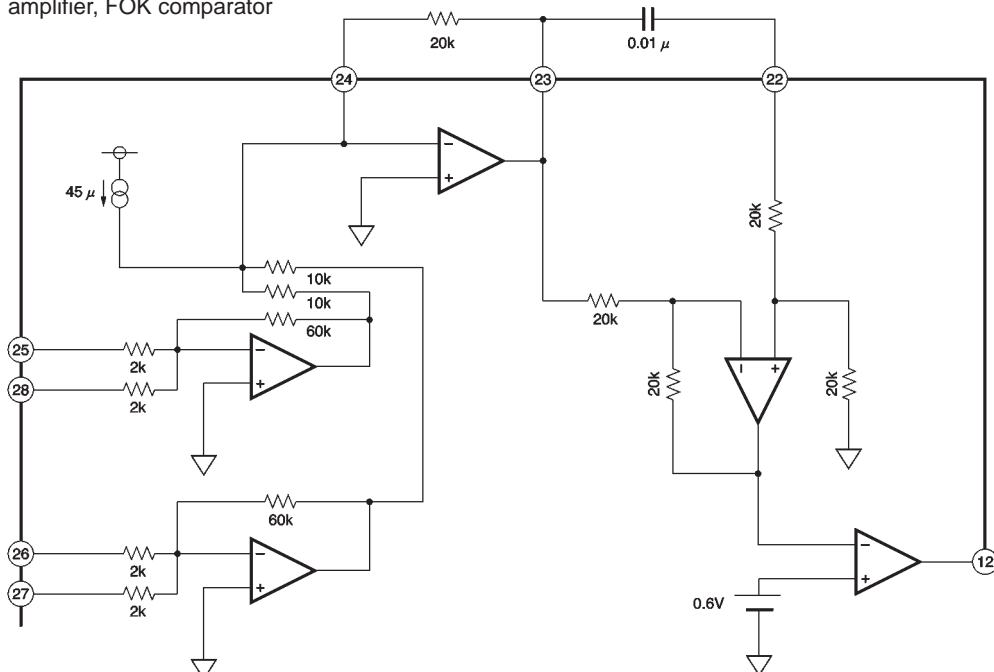


Fig.2 RF and FOK block

RFO is shifted downwards from V_B by 0.9V. However, the resistance between pins 23 and 24 is set to $20k\Omega$ and if this resistance is changed use external components to adjust the shift back to 0.9V. Have the feedback resistance $10k\Omega$ or greater. If the DC component of RF rises 0.3V, then FOK becomes high.

(2) FE amplifier and focus search

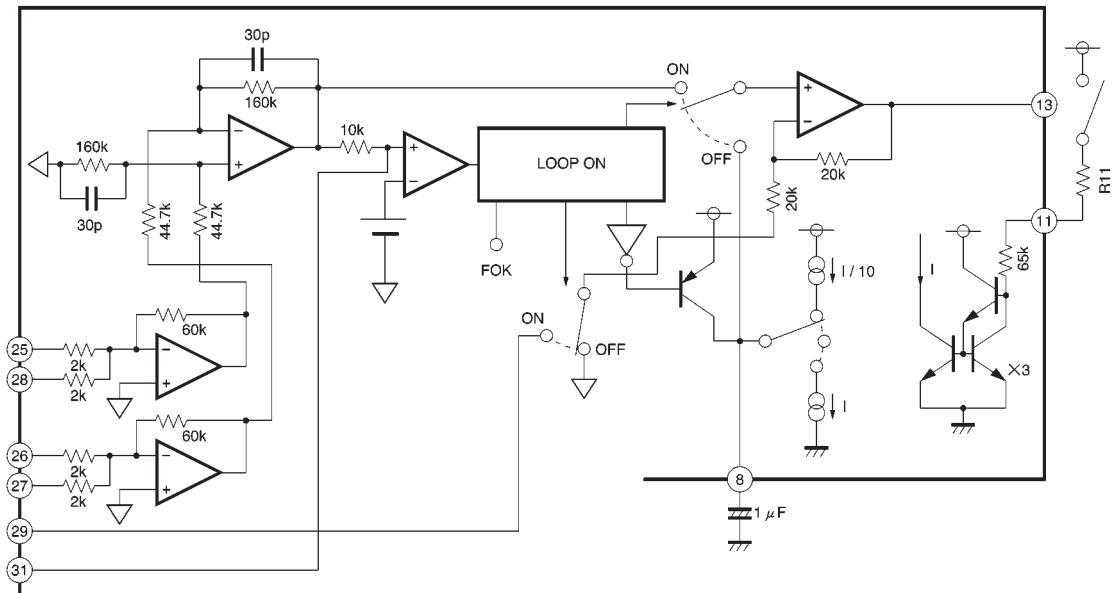


Fig.3 Focus error block

The voltage for focus search is obtained by the charging and discharging of the capacitor attached to pin 8. The charging current is $I/10$ and the discharging current is I . The FEO output amplitude (V_{SERCH}) at this time is determined by the formula given below.

$$V_{SERCH} = \pm I \times 15k\Omega \times 2 (V_B \text{ reference})$$

Moreover, from Fig.3, I can be approximated by the formula given below.

$$I = \frac{V_{CC} - 1.4}{65k + R11} \times \frac{1}{3}$$

Set $R11$ so that I becomes $2\mu A$ or greater. Apply biasing to the focus error signal from pin 29. If no adjustment occurs, pin 29 = V_B .

The timing charts when the focus loop turns ON or OFF are given on the next page.

1) LOOP ON timing

When FOK turns high, the fall of FE' is detected and the FOCUS LOOP turns ON.

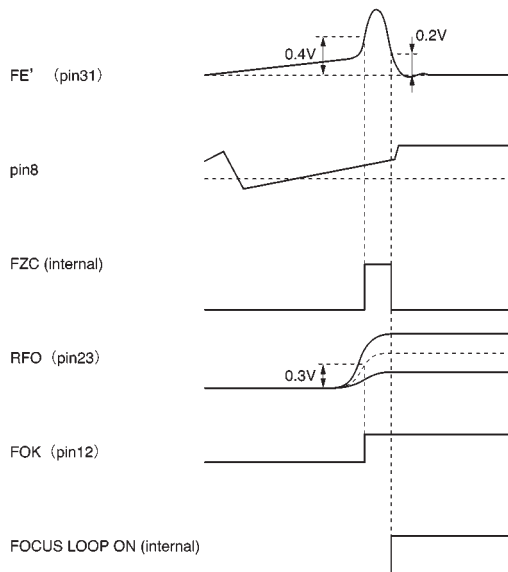


Fig.4 LOOP ON timing

2) LOOP OFF timing

After FOK turns low, the FOCUS LOOP turns OFF after the delay T (s) shown in the figure below.

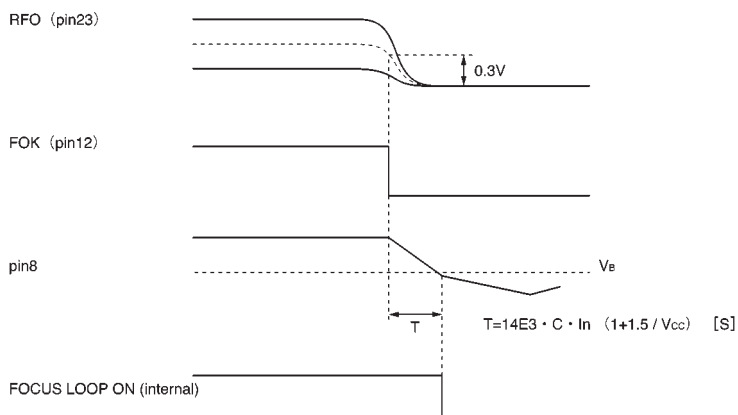


Fig.5 LOOP OFF timing

(3) APC block and AGC block

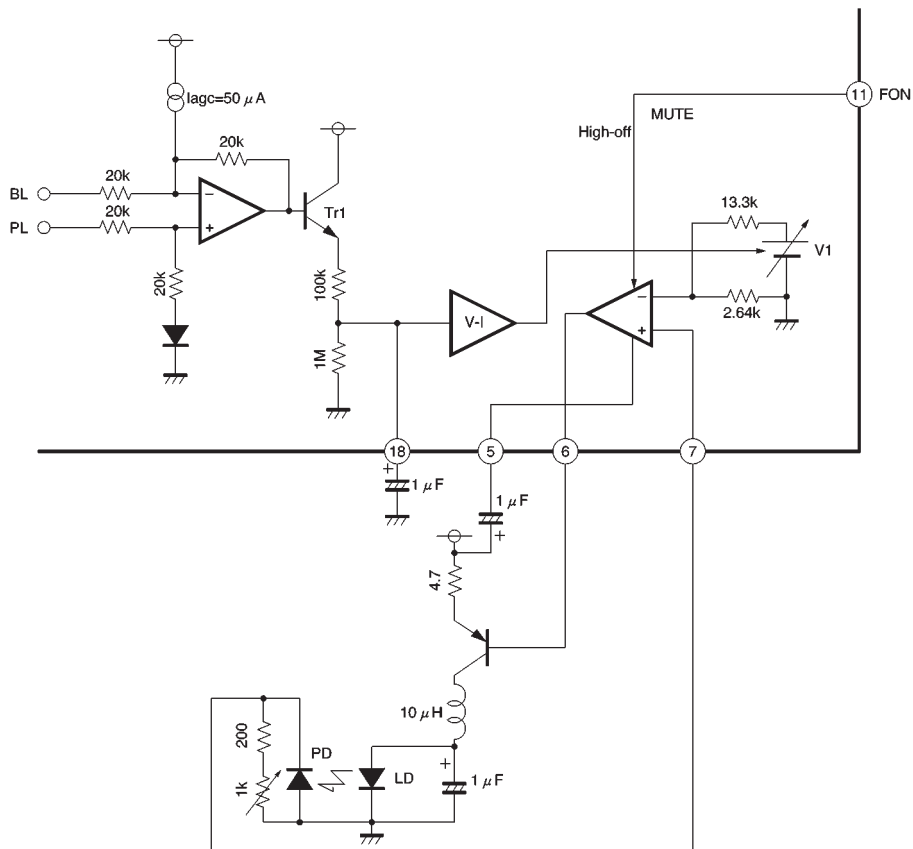


Fig.6 APC and AGC blocks

The initial setting for V1 is 1.2V. When PL-BL (the RF AC amplitude) exceeds a certain value (V_{AGC}), then AGC lowers V1 and suppresses the laser power. The value of V_{AGC} is $(50\mu A \times 20k) = 1V$.

When defect turns high, Tr1 turns OFF. When FON (pin 11) is low, the LD output (pin 6) becomes high.

Fig.7 DET block

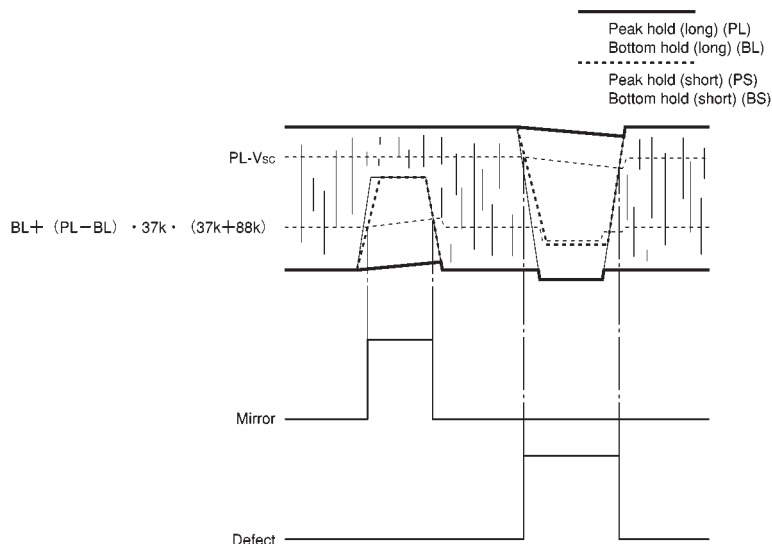


Fig.8 Defect and mirror generation

$$V_{SC} = \frac{1.2}{R_9 + 200} \times 4k$$

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●Application example

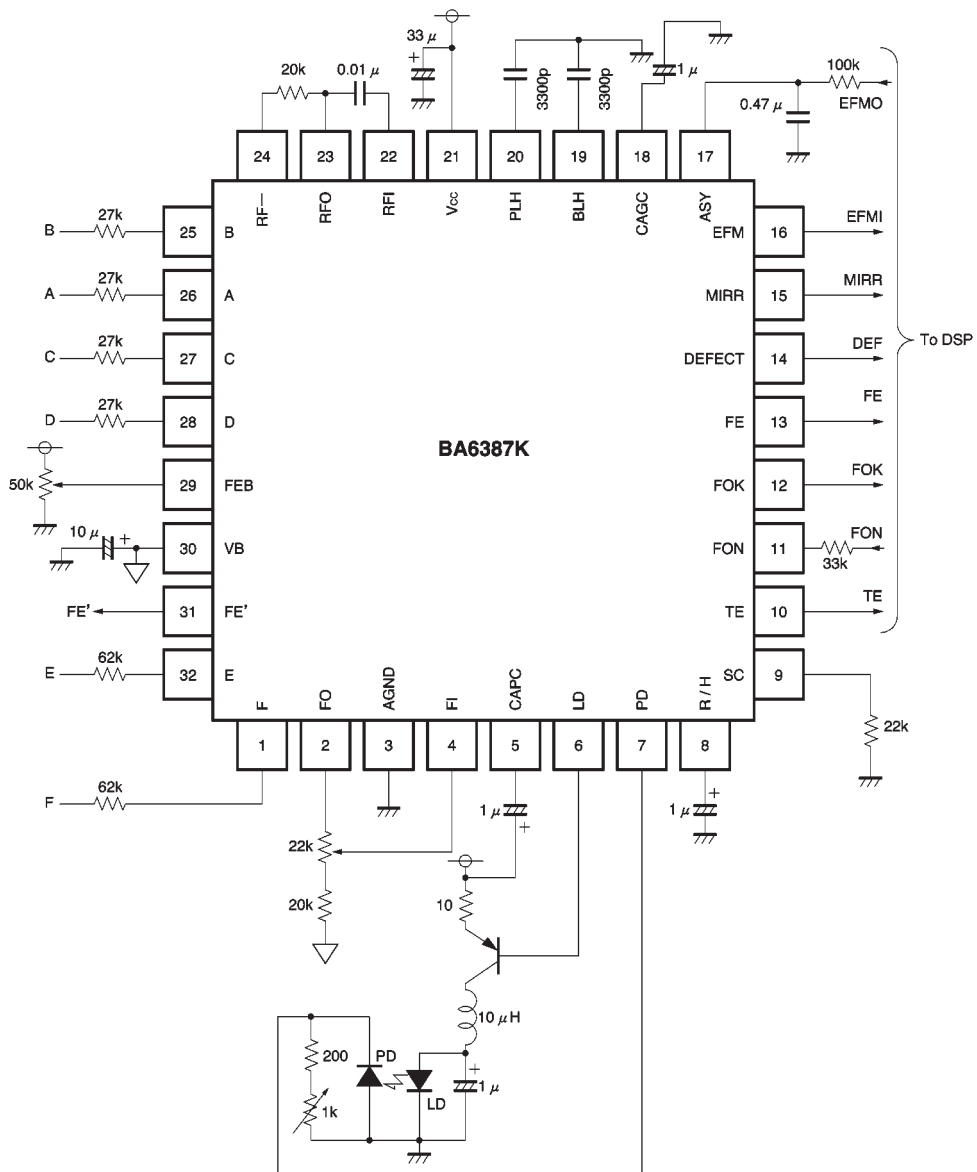


Fig.9

●Electrical characteristics curves

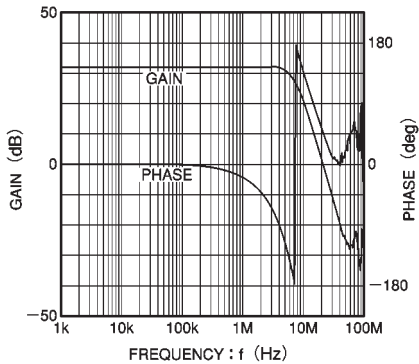


Fig.10 RF amplifier frequency characteristics

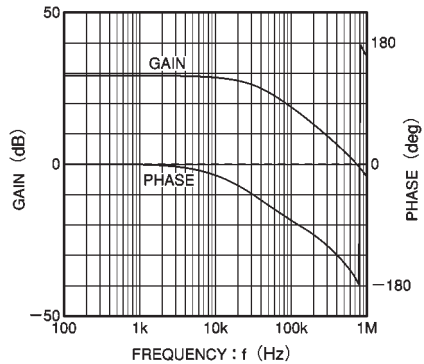


Fig.11 FE amplifier frequency characteristics

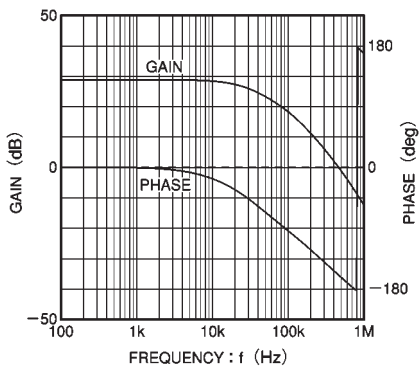
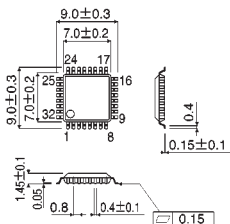


Fig.12 TE amplifier frequency characteristics

● External dimensions (Units: mm)



QFP32